
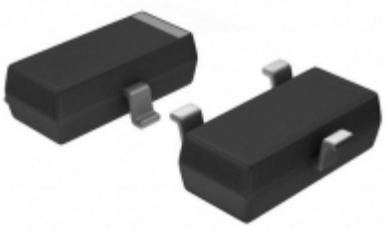


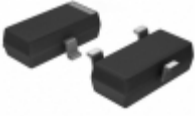





	<h2>SI2329DS-T1-GE3</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">SI2329DS-T1-GE3</a></p> <p><b>Hersteller / Marke:</b> <a href="#">Electro-Films (EFI) / Vishay</a></p> <p><b>Teil der Beschreibung:</b> MOSFET P-CH 8V 6A SOT-23</p> <p><b>Datenblätter:</b>  <a href="#">SI2329DS-T1-GE3.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 106341 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">SI2329DS-T1-GE3</a>
Hersteller	<a href="#">Electro-Films (EFI) / Vishay</a>
Beschreibung	MOSFET P-CH 8V 6A SOT-23
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	106341 pcs Stock
detaillierte Beschreibung	P-Channel 8V 6A (Tc) 2.5W (Tc) Surface Mount SOT-
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Verlustleistung (max)	2.5W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	8V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	6A (Tc)
Rds On (Max) @ Id, Vgs	30 mOhm @ 5.3A, 4.5V
VGS (th) (Max) @ Id	800mV @ 250µA
Gate Charge (Qg) (Max) @ Vgs	29nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	1485pF @ 4V
Antriebsspannung (Max Rds On, Min Rds On)	1.2V, 4.5V
Vgs (Max)	±5V
Verpackung	Cut Tape (CT)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SI2329DS-T1-GE3CT









SI2329DS-T1-GE3 ist neu im Original, Suche SI2329DS-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI2329DS-T1-GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI2329DS-T1-GE3: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>SI2331DS</b> VISHAY SI2331DS VISHAY</p>	 <p><b>SI2329DS-T1-GE3</b> Vishay / Siliconix MOSFET P-CH 8V 6A SOT-23</p>	 <p><b>SI2328DS-T1-E3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 100V 1.15A SOT23-3</p>	 <p><b>SI2331DS-T1-E3</b> Vishay / Siliconix MOSFET P-CH 12V 3.2A SOT23-3</p>
 <p><b>SI2329DS-T1-E3</b> VISHAY SI2329DS-T1-E3 VISHAY</p>	 <p><b>SI2331DS-T1-E3</b> Electro-Films (EFI) / Vishay MOSFET P-CH 12V 3.2A SOT23-3</p>	 <p><b>SI2328DS-T1-GE3</b> Vishay / Siliconix MOSFET N-CH 100V 1.15A SOT-23</p>	 <p><b>SI2331/SK2331A</b> Original SOT-23</p>

### heiße Teile

Mehr

 SI2323DDS-T1-GE3	 SI2323DS	 SI2323DS-T1-E3	 SI2323DS-T1-E3	 SI2323DS-T1-GE3
 SI2323DS-T1-GE3	 SI2324DS-T1-E3	 SI2324DS-T1-GE3	 SI2324DS-T1-GE3	 SI2325DS-T1-E3
 SI2325DS-T1-E3	 SI2325DS-T1-GE3	 SI2325DS-T1-GE3	 SI2327DS-T1-E3	 SI2327DS-T1-E3
 SI2327DS-T1-GE3	 SI2327DS-T1-GE3	 SI2328DS	 SI2328DS-T1	 SI2328DS-T1-E3
 SI2328DS-T1-E3	 SI2328DS-T1-GE3	 SI2328DS-T1-GE3	 SI2329DS-T1-E3	 SI2329DS-T1-GE3
 SI2331DS	 SI2331DS-T1-E3	 SI2331DS-T1-E3	 SI2331DS-T1-GE3	 SI2331DS-T1-GE3
 SI2333ADS-T1-GE3	 SI2333CDS	 SI2333CDS-T1-E3	 SI2333CDS-T1-E3	 SI2333CDS-T1-GE3
 SI2333CDS-T1-GE3	 SI2333DDS-T1-E3	 SI2333DDS-T1-GE3	 SI2333DDS-T1-GE3	 SI2333DS
 SI2333DS-T1-E3	 SI2333DS-T1-E3	 SI2333DS-T1-GE3	 SI2333DS-T1-GE3	 SI2334DS-T1-E3
 SI2334DS-T1-GE3	 SI2334DS-T1-GE3	 SI2335DS-T1	 SI2335DS-T1-E3	 SI2335DS-T1-E3

Contact us:[Info@Y-IC.com](mailto:Info@Y-IC.com)

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